

**GBU806G THRU GBU810G**

**BRIDGE RECTIFIERS**



<b>VOLTAGE</b>	600~1000 Volts	<b>CURRENT</b>	8.0 Amperes	<b>GBU</b>	<b>Marking &amp; Schematic diagram</b>
<b>FEATURES</b>					
<ul style="list-style-type: none"> <li>• Glass passivated die construction</li> <li>• low forward voltage drop</li> <li>• High current capability</li> <li>• High surge current capability</li> <li>• Plastic material-UL flammability 94V-0</li> </ul>					
<b>MECHANICAL DATA</b>					
<ul style="list-style-type: none"> <li>• Case: GBU , olded lastic</li> <li>• Terminals: Plated Leads Solderable per MIL-STD-202, Method 208</li> <li>• Polarity: As Marked on Case</li> <li>• Mounting Position: Any</li> <li>• Lead Free: For RoHS / Lead Free Version</li> </ul>					
<b>TYPICAL APPLICATIONS</b>					
<ul style="list-style-type: none"> <li>• For use in low voltage ,high frequency inverters ,DC/DC converters,free wheeling ,and polarity protection applications</li> </ul>					

PIN	DISCRIPTION
1	Output Cathode(-)
2	Input Pin(AC1)
3	Input Pin(AC2)
4	Output Anode(+)

**Remark:**

- ①. NH=niuhang trademark
- ②. FF=Product line code,According to actual changes  
YWW=Data code,According to actual changes  
EDDKF=Inernal code,According to actual changes
- ③. GBU8xxG=Modle,xx=06,08,10
- ④. "- AC +"=Polarity mark

Single phase,half wave,60Hz,resistive or inductive load.For capacitive load,derate current by 20%

**Maximum Ratings** (Ratings at 25°C ambient temperature unless otherwise specified )

Parameter	Symbol	GBU806G	GBU808G	GBU810G	Unit
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	600	800	1000	V
Maximum RMS Voltag	$V_{RMS}$	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	600	800	1000	V
Maximum Average Forward Rectified Current @ TC=100°C (see fig.1)	$I_{F(AV)}$	8 2.9			A
Peak Forward Surge Current 8.3ms Single Half Sine-wave Superimposed On Rate Load (JEDEC Method)	$I_{FSM}$	175			A
Current Squared Time Per Diode(t<8.3ms)	$I^2 t$	127.09			A <sup>2</sup> sec

**Electrical Characteristcs** (Ratings at 25°C ambient temperature unless otherwise specified )

Parameter	Symbol	GBU806G	GBU808G	GBU810G	Unit
Maximum Forward Voltage Per Diode @4.0A (Note 1)	$V_{FM}$	1.0			V
Maximum DC Reverse Current at Rated DC Blocking Voltage (Note 2)	$I_{RRM}$	5 300			uA
Typical Junction Capacitance Per Diode (Note 3)	$C_J$	50			pF

**Thermal Characteristics** (Ratings at 25°C ambient temperature unless otherwise specified )

Parameter	Symbol	GBU806G	GBU808G	GBU810G	Unit
Operating Junction Temperature Range	$T_J$	-55 to +150			°C
Storage Temperature Range	$T_{STD}$	-55 to +150			
Typical thermal resistance (Note 4)	$R_{\theta JA}$ $R_{\theta JC}$	25.0 2.0			°C/W

- Notes: 1. Pulse test: 300 μs pulse width,1% duty cycle  
 2. Pulse test: pulse width ≤40ms  
 3. Measured at 1 MHZ and applied reverse voltage of 4.0 VDC.  
 4. Device mounted on Device mounted on 75mm x 45mm x 5.5mm Aluminum Plate Heatsink.

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**RATING AND CHARACTERISTIC CURVES**

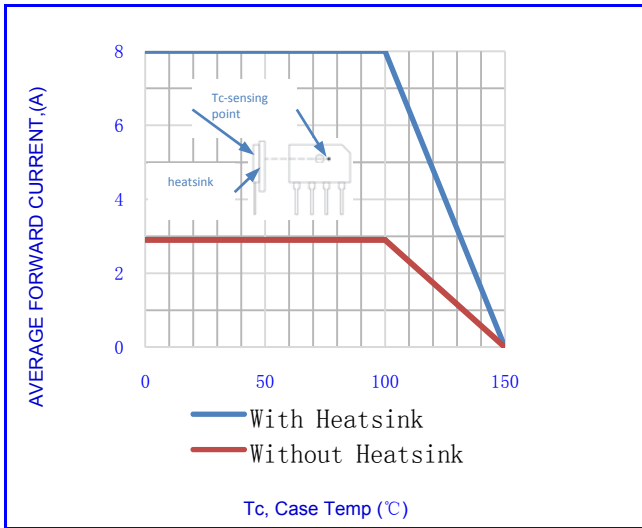


Fig.1-FORWARD CURRENT DERATING CURVE

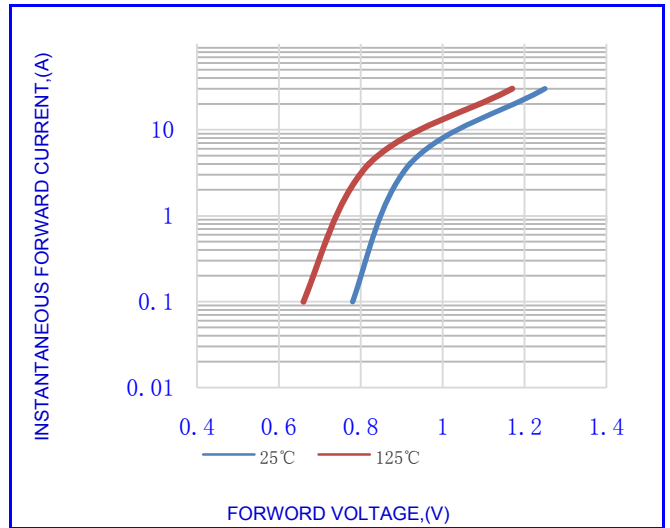


Fig.2- TYPICAL INSTANTANEOUS FORWARD

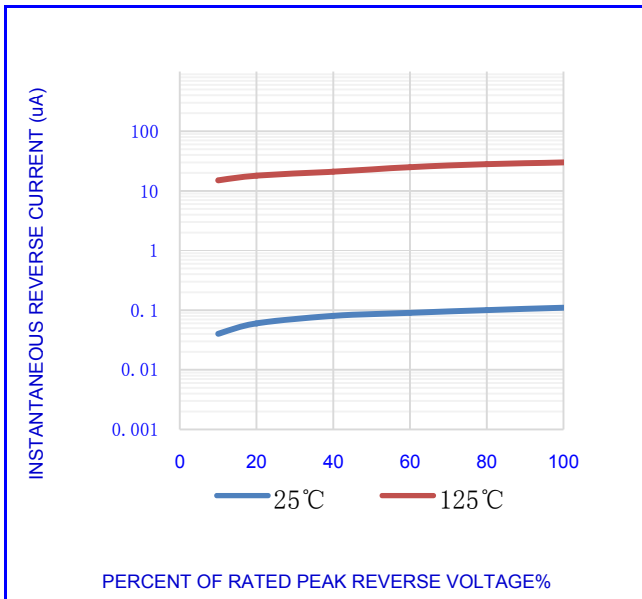


Fig.3- TYPICAL REVERSE CHARACTERISTICS

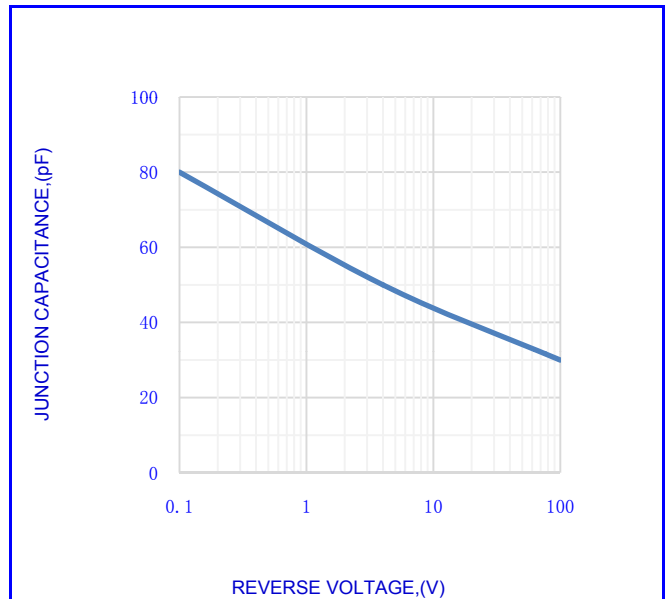


Fig.4- TYPICAL JUNCTION CAPACITANCE

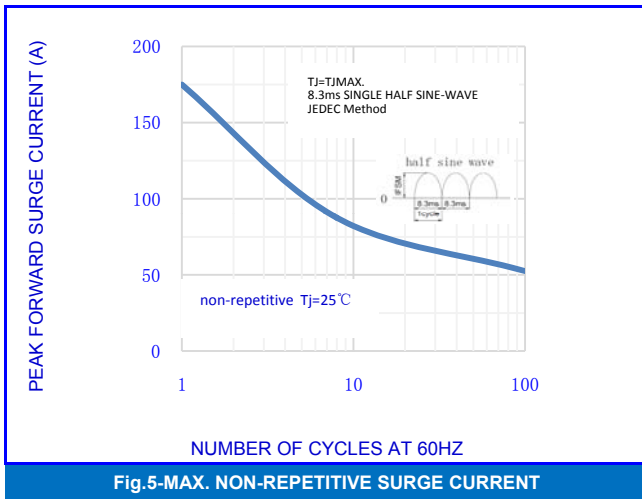


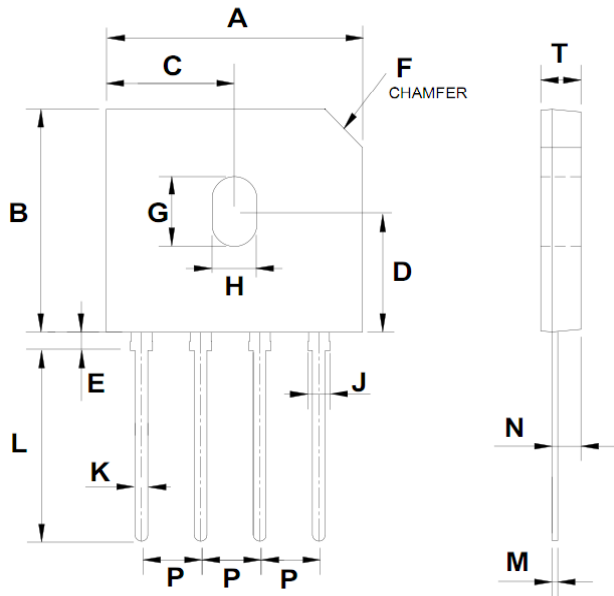
Fig.5-MAX. NON-REPETITIVE SURGE CURRENT

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**OUTLINE DRAWINGS**



OUTLINE DIMENSIONS						
DIM	MILLIMETERS			INCHES		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	21.50	-	23.50	0.85	-	0.93
B	18.30	-	19.10	0.72	-	0.75
C	10.90	-	11.10	0.43	-	0.44
D	9.80	-	10.20	0.39	-	0.40
E	1.70	-	2.40	0.07	-	0.09
F	-	3.2°/45°	-	-	3.2°/45°	-
G	5.50	-	5.90	0.22	-	0.23
H	3.50	-	3.90	0.14	-	0.15
J	2.00	-	2.40	0.08	-	0.09
K	0.90	-	1.20	0.04	-	0.05
L	17.27	-	18.29	0.68	-	0.72
M	0.40	-	0.60	0.02	-	0.02
N	2.30	-	2.70	0.09	-	0.11
P	4.80	-	5.30	0.19	-	0.21
T	3.30	-	3.60	0.13	-	0.14

**GBU**

**Packing Information**

Package	Pack	Quantity (pcs/box)	Box Size L×W×H (mm)	Carton Size L×W×H (mm)	Quantity (box/carton)
GBU	B/P	250	230×45×120	380×240×190	12

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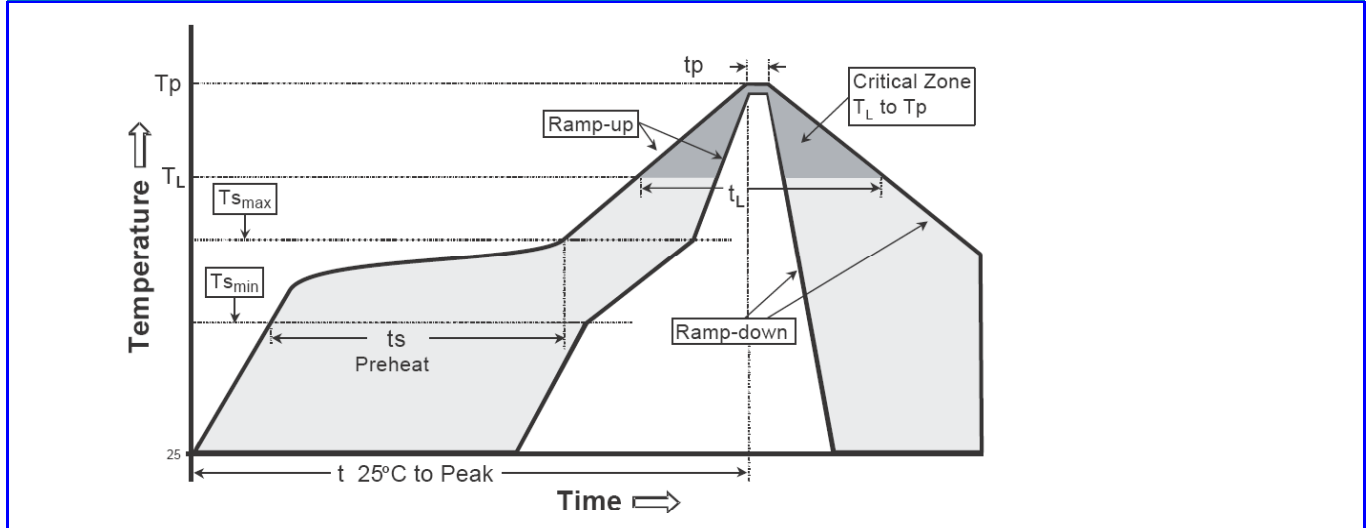
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**Recommended wave soldering condition**

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

**Recommended temperature profile for IR reflow**



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T <sub>smax</sub> to T <sub>p</sub> )	3°C/second max.	3°C/second max.
Preheat -Temperature Min(T <sub>Smin</sub> ) -Temperature Max(T <sub>Smax</sub> ) -Time(t <sub>s</sub> min to t <sub>s</sub> max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (T <sub>L</sub> ) - Time (t <sub>L</sub> )	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(T <sub>P</sub> )	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

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